

IN THE SPECIFICATION:

Page 1, paragraph [0002] please amend as follows:

An element attracting attention at present as a variable capacitance element replacing the variable capacitance diode is a MOS capacitance element. In application to a temperature compensated crystal ~~resonator~~ oscillator (hereinafter referred to as TCXO) used for, for example, portable telephones or the like, the MOS capacitance element has a feature that a large capacitance change is obtained even if a voltage change is light. Even in situations where the voltage used for oscillation circuits becomes low and the voltage that can be applied to the variable capacitance element must be made low, therefore, the MOS capacitance element has sufficient capacitance characteristics in practical use.